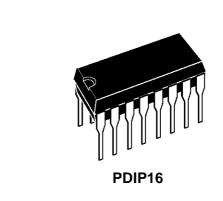


## ST6200L/01L/03L

# LOW VOLTAGE 8-BIT ROM MCUs WITH A/D CONVERTER, AND 16 PINS

- 2.4 to 3.9V Supply Operating Range
- 4 MHz Maximum Clock Frequency
- 0 to +70°C Operating Temperature Range
- Run, Wait and Stop Modes
- 5 Interrupt Vectors
- Look-up Table capability in Program Memory
- Data Storage in Program Memory: User selectable size
- Data RAM: 64bytes
- 9 I/O pins, fully programmable as:
  - Input with pull-up resistor
  - Input without pull-up resistor
  - Input with interrupt generation
  - Open-drain or push-pull output
  - Analog Input (except ST6203L)
- 3 I/O lines can sink up to 12mA to drive LEDs
- 8-bit Timer/Counter with 7-bit programmable prescaler
- Digital Watchdog
- 8-bit A/D Converter with up to 4 analog inputs
- On-chip Clock oscillator can be driven by Quartz Crystal Ceramic resonator or RC network
- Power-on Reset
- One external Non-Maskable Interrupt
- ST626x-EMU2 Emulation and Development System (connects to an MS-DOS PC via an RS232 serial line)





**PSO16** 

(See end of Datasheet for Ordering Information)

#### **DEVICE SUMMARY**

DEVICE	ROM (Bytes)	I/O Pins	Analog inputs
ST6200L	1036	9	4
ST6201L	1836	9	4
ST6203L	1036	9	None

Rev. 1.0

November 1997 1/10

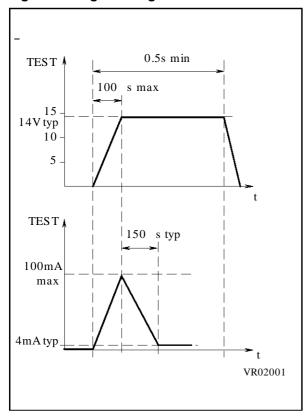
#### 1 GENERAL DESCRIPTION

#### 1.1 INTRODUCTION

The ST6200L/01L and 03L are low voltage mask programmed ROM version of ST62T00C,T01C and T03C OTP devices.

They offer the same functionality as OTP devices, selecting as ROM options the options defined in the programmable option byte of the OTP version, with the exception of the LVD Reset and the OSG that are not available.

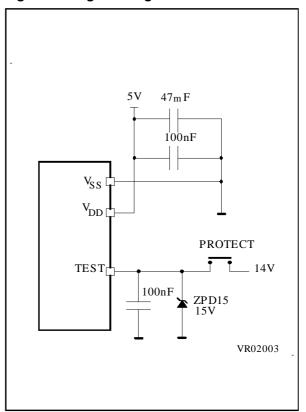
Figure 1. Programming wave form



#### 1.2 ROM READOUT PROTECTION

If the ROM READOUT PROTECTION option is selected, a protection fuse can be blown to prevent any access to the program memory content. In case the user wants to blow this fuse, high voltage must be applied on the TEST pin.

Figure 2. Programming Circuit



Note: ZPD15 is used for overvoltage protection

ST62	200L/01L/03L MICRO	CONTROLLER OPTION LIST
Customer		
Address		
Contact		
Phone No		
Reference		• • •
SGS-THOMSON Micro	electronics references	;
Device: [] ST6200l	_ []ST6201L	[] ST6203L
Package:	[] Dual in Line P	lastic[] Small Outline Plastic with conditionning:
-		[] Standard (Stick)
		[] Tape & Reel
Temperature Range:	[] 0°C to + 70°C	
Special Marking:	[ ] No	[]Yes ""
Authorized characters a	are letters, digits, '.', '-'	, '/' and spaces only.
Maximum character co	unt: DIP16:	9
	SO16:	6
Oscillator Source Selec	tion: [ ] Crystal Quartz	/Ceramic resonator
	[] RC Network	
Watchdog Selection:	[] Software Activ [] Hardware Acti	
ROM Readout Protection	on: [] Disabled (Fuse	e cannot be blown)
	[] Enabled (Fuse	e can be blown by the customer)
Note:	No part is deliver The fuse must be	red with protected ROM. e blown for protection to be effective.
External STOP Mode C	Control 1 Enabled	[] Disabled
NMI pin pull-up	[ ] Enabled	[] Disabled
Min pin pun-up	[] Lilabled	[] Disabled
Comments:		
Supply Operating Rang	e in the application:	
Oscillator Fequency in	the application:	
Notes		•••
Signature		
Date		

#### 1.3 ORDERING INFORMATION

The following section deals with the procedure for transfer of customer codes to SGS-THOMSON.

#### 1.3.1 Transfer of Customer Code

Customer code is made up of the ROM contents and the list of the selected mask options. The ROM contents are to be sent on diskette, or by electronic means, with the hexadecimal file generated by the development tool. All unused bytes must be set to FFh.

The selected mask options are communicated to SGS-THOMSON using the correctly filled OP-TION LIST appended.

#### 1.3.2 Listing Generation and Verification

When SGS-THOMSON receives the user's ROM contents, a computer listing is generated from it. This listing refers exactly to the mask which will be used to produce the specified MCU. The listing is then returned to the customer who must thoroughly check, complete, sign and return it to SGS-THOMSON. The signed listing forms a part of the contractual agreement for the creation of the specific customer mask.

The SGS-THOMSON Sales Organization will be pleased to provide detailed information on contractual points.

Table 1. ROM Memory Map for ST6200L,03L

Device Address	Description
0000h-0B9Fh	Reserved
0BA0h-0F9Fh	User ROM
0FA0h-0FEFh	Reserved
0FF0h-0FF7h	Interrupt Vectors
0FF8h-0FFBh	Reserved
0FFCh-0FFDh	NMI Interrupt Vector
0FFEh-0FFFh	Reset Vector

Table 2. ROM Memory Map for ST6201L

Device Address	Description
0000h-087Fh	Reserved
0880h-0F9Fh	User ROM
0FA0h-0FEFh	Reserved
0FF0h-0FF7h	Interrupt Vectors
0FF8h-0FFBh	Reserved
0FFCh-0FFDh	NMI Interrupt Vector
0FFEh-0FFFh	Reset Vector

**Table 3. ROM version Ordering Information** 

Sales Type	ROM	Analog inputs	Temperature Range	Package
ST6200LB1/XXX	1026 Putos		0 to +70°C	PDIP16
ST6200LM1/XXX	1036 Bytes	4		PSO16
ST6201LB1/XXX	1926 Putos			PDIP16
ST6201LM1/XXX	1836 Bytes			PSO16
ST6203LB1/XXX	1026 Putos	None		PDIP16
ST6203LM1/XXX	1036 Bytes	None		PSO16

#### **2 ELECTRICAL CHARACTERISTICS**

#### 2.1 ABSOLUTE MAXIMUM RATINGS

This product contains devices to protect the inputs against damage due to high static voltages, however it is advisable to take normal precaution to avoid application of any voltage higher than the specified maximum rated voltages.

For proper operation it is recommended that  $V_{\rm and}$   $V_{\rm O}$  be higher than  $V_{\rm SS}$  and lower than  $V_{\rm DD}$ . Reliability is enhanced if unused inputs are connected to an appropriate logic voltage level ( $V_{\rm DD}$  or  $V_{\rm SS}$ ).

**Power Considerations.** The average chip-junction temperature, Tj, in Celsius can be obtained from:

Tj=TA + PD x RthJA

Where:TA = Ambient Temperature.

RthJA =Package thermal resistance (junction-to ambient).

PD = Pint + Pport.

Pint =IDD x VDD (chip internal power).

Pport =Port power dissipation (determined by the user).

Symbol	Parameter	Value	Unit
$V_{DD}$	Supply Voltage	-0.3 to 7.0	V
V <sub>I</sub>	Input Voltage	$V_{SS}$ - 0.3 to $V_{DD}$ + 0.3 <sup>(1)</sup>	V
V <sub>O</sub>	Output Voltage	$V_{SS}$ - 0.3 to $V_{DD}$ + 0.3 <sup>(1)</sup>	V
I <sub>O</sub>	Current Drain per Pin Excluding V <sub>DD</sub> , V <sub>SS</sub>	±10	mA
$IV_{DD}$	Total Current into V <sub>DD</sub> (source)	50	mA
IV <sub>SS</sub>	Total Current out of V <sub>SS</sub> (sink)	50	mA
Tj	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-60 to 150	°C

#### Notes:

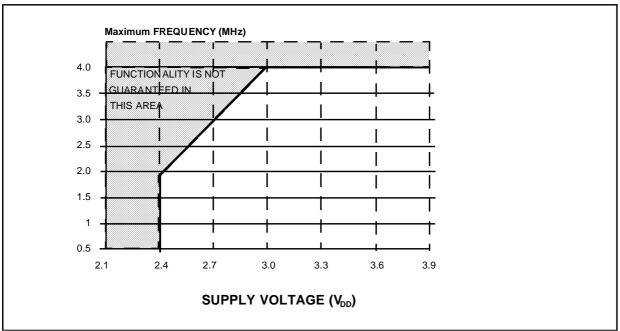
- Stresses above those listed as "absolute maximum ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.
- (1) Within these limits clamping diodes are guarantee to be not conductive. Voltages outside these limits are authorised as long as injection current is kept within the specification.

#### 2.2 RECOMMENDED OPERATING CONDITIONS

Symbol Parameter	Parameter	Test Conditions		Unit		
	rest Conditions	Min.	Тур.	Max.		
T <sub>A</sub>	Operating Temperature	1 Suffix Version	0		70	°C
V <sub>DD</sub>	Operating Supply Voltage	$f_{OSC} = 2MHz$ $f_{OSC} = 4MHz$	2.4 3		3.9 3.9	V
fosc	Oscillator Frequency <sup>2)</sup>	$V_{DD} = 2.4V$ $V_{DD} = 3.0V$	0 0		2.0 4.0	MHz
I <sub>INJ+</sub>	Pin Injection Current (positive)	$V_{DD} = 2.4 \text{ to } 3.9 \text{V}$			+5	mA
I <sub>INJ-</sub>	Pin Injection Current (negative)	$V_{DD} = 2.4 \text{ to } 3.9 \text{V}$			-5	mA

#### Notes:

Figure 3. Maximum Operating FREQUENCY (Fmax) Versus SUPPLY VOLTAGE (YD)



The shaded area is outside the recommended operating range; device functionality is not guaranteed under these conditions.

<sup>1.</sup> Care must be taken in case of negative current injection, where adapted impedance must be respected on analog sources to not affect the A/D conversion. For a -1mA injection, a maximum 10 K $\Omega$  is recommended.

<sup>2.</sup>An oscillator frequency above 1MHz is recommended for reliable A/D results

### 2.3 DC ELECTRICAL CHARACTERISTICS

 $(T_A = 0 \text{ to } +70^{\circ}\text{C unless otherwise specified})$ 

		<b>-</b>		Value		
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V <sub>IL</sub>	Input Low Level Voltage All Input pins				V <sub>DD</sub> x 0.2	V
V <sub>IH</sub>	Input High Level Voltage All Input pins		V <sub>DD</sub> x 0.8			V
V <sub>Hys</sub>	Hysteresis Voltage <sup>(1)</sup> All Input pins	V <sub>DD</sub> = 3V	0.2			V
Low Level Output Voltage All Output pins	Low Level Output Voltage All Output pins	$V_{DD}$ = 3.0V; $I_{OL}$ = +10 $\mu$ A $V_{DD}$ = 3.0V; $I_{OL}$ = + 3.0mA $V_{DD}$ = 2.4V; $I_{OL}$ = + 1.5mA			0.1 0.8 0.8	
V <sub>OL</sub>	Low Level Output Voltage 20 mA Sink I/O pins	$V_{DD}$ = 3.0V; $I_{OL}$ = +10 $\mu$ A $V_{DD}$ = 3.0V; $I_{OL}$ = +8 $m$ A $V_{DD}$ = 3.0V; $I_{OL}$ = +12 $m$ A $V_{DD}$ = 2.4V; $I_{OL}$ = +5 $m$ A			0.1 0.8 1.3 0.8	V
V <sub>OH</sub>	High Level Output Voltage All Output pins	$V_{DD} = 3.0V; I_{OH} = -10\mu A$ $V_{DD} = 3.0V; I_{OH} = -1.5mA$ $V_{DD} = 2.4V; I_{OH} = -10\mu A$	2.9 2.0 2.3			V
R <sub>PU</sub>	Pull-up Resistance	All Input pins	100	250	600	ΚΩ
1,50	-	RESET pin	400	600	1200	1132
I <sub>IL</sub>	Input Leakage Current All Input pins but RESET	$V_{IN} = V_{SS}$ (No Pull-Up configured) $V_{IN} = V_{DD}$		0.1	1.0	μА
I <sub>IH</sub>	Input Leakage Current RESET pin	$V_{IN} = V_{SS}$ $V_{IN} = V_{DD}$	-8	-16	-30 10	μΛ
	Supply Current in RESET Mode	V <sub>RESET</sub> =V <sub>SS</sub> f <sub>OSC</sub> =4MHz			1.5	mA
I	Supply Current in RUN Mode <sup>(2)</sup>	V <sub>DD</sub> =3.0V f <sub>INT</sub> =4MHz	_	_	1.5	mA
I <sub>DD</sub>	Supply Current in WAIT Mode <sup>(3)</sup>	V <sub>DD</sub> =3.0V f <sub>INT</sub> =4MHz			0.5	mA
	Supply Current in STOP Mode <sup>(3)</sup>	I <sub>LOAD</sub> =0mA V <sub>DD</sub> =3.0V			2	μА

#### Notes

- (1) Hysteresis voltage between switching levels
- (2) All peripherals running
- (3) All peripherals in stand-by

## DC ELECTRICAL CHARACTERISTICS(Cont'd)

#### 2.4 AC ELECTRICAL CHARACTERISTICS

 $((T_A = 0 \text{ to } +70^{\circ}\text{C unless otherwise specified})$ 

Symbol	Parameter	Test Conditions		Value		Unit
	raiailietei	rest Conditions	Min.	Тур.	Max.	
t <sub>REC</sub>	Supply Recovery Time (1)		100			ms
f <sub>RC</sub>	Internal frequency with RC oscillator <sup>2) 3)</sup>	VDD=3.0V $R=47kΩ$ $R=100kΩ$ $R=470kΩ$	2.5 1.4 450	3 1.7 520	3.5 2.1 600	MHz MHz kHz
C <sub>IN</sub>	Input Capacitance	All Inputs Pins			10	pF
C <sub>OUT</sub>	Output Capacitance	All Outputs Pins			10	pF

Notes: 1. Period for which  $V_{DD}$  has to be connected at 0V to allow internal Reset function at next power-up.

<sup>2</sup> An oscillator frequency above 1MHz is recommended for reliable A/D results.

<sup>3.</sup> Measure performed with OSCin pin soldered on PCB, with an around 2pF equivalent capacitance.

### 2.5 A/D CONVERTER CHARACTERISTICS

 $(T_A = 0 \text{ to } +70^{\circ}\text{C unless otherwise specified})$ 

Symbol	Parameter	Test Conditions		Value		Unit
Symbol		rest Conditions	Min.	Тур.	Max.	
Res	Resolution			8		Bit
A <sub>TOT</sub>	Total Accuracy (1) (2)	$\begin{array}{l} f_{\rm OSC} > 1.2 {\rm MHz},  {\rm V_{DD}}{=}3.0 {\rm V} \\ f_{\rm OSC} > 1.2 {\rm MHz},  {\rm V_{DD}}{=}2.4 {\rm V} \\ f_{\rm OSC} > 32 {\rm kHz},  {\rm V_{DD}}{=}3.0 {\rm V} \end{array}$			±25 ±35 ±50	mV
t <sub>C</sub>	Conversion Time	$f_{OSC} = 2MHz$ $f_{OSC} = 4 MHz$		280 140		μs
ZIR	Zero Input Reading	Conversion result when $V_{IN} = V_{SS}$	00			Hex
FSR	Full Scale Reading	Conversion result when $V_{IN} = V_{DD}$			FF	Hex
ADI	Analog Input Current During Conversion	V <sub>DD</sub> = 4.0V			1.0	μΑ
AC <sub>IN</sub>	Analog Input Capacitance			2	5	pF

- Notes:
  1. Noise at VDD, VSS <10mV
  2. With oscillator frequencies less than 1MHz, the A/D Converter accuracy is decreased.

### 2.6 TIMER CHARACTERISTICS

 $((T_A = 0 \text{ to } +70^{\circ}\text{C unless otherwise specified})$ 

Symbol	Parameter	Test Conditions		Unit		
			Min.	Тур.	Max.	Onic
f <sub>IN</sub>	Input Frequency on TIMER Pin					MHz
t <sub>W</sub>	Pulse Width at TIMER Pin	V <sub>DD</sub> = 2.4V	250			ns

#### ST6200L/01L/03L

Notes:

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